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Complementary power Darlingtons

Features

- Complementary transistors in monolithic Darlingtons configuration
- Integrated collector-emitter antiparallel diode

Applications

- Audio power amplifier
- DC-AC converter
- General purpose switching applications

Description

The 2N6284 is an epitaxial-base NPN power transistor in monolithic Darlingtons configuration mounted in TO-3 metal case. It is intended for general purpose amplifier and low frequency switching applications. The complementary PNP type is 2N6287.

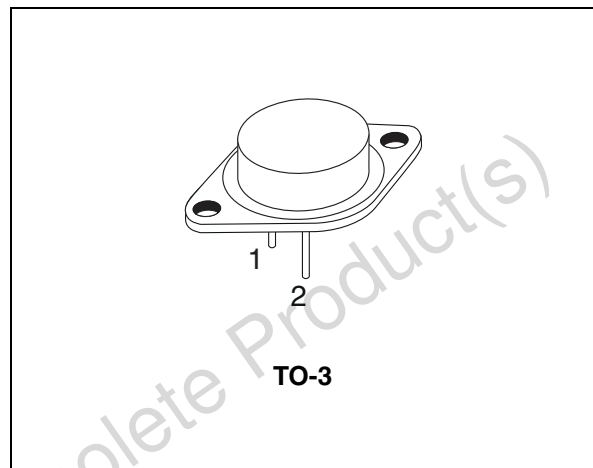


Figure 1. Internal schematic diagrams

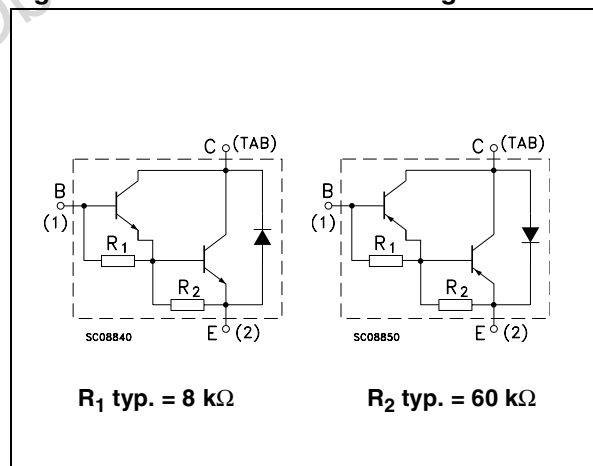


Table 1. Device summary

Order code	Marking	Package	Packaging
2N6284	2N6284	TO-3	Bag
2N6287	2N6287		

1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		NPN	2N6284	
		PNP	2N6287	
V_{CBO}	Collector-base voltage ($I_E = 0$)		100	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)		100	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)		5	V
I_C	Collector current		20	A
I_{CM}	Collector peak current ($t_p < 5$ ms)		40	A
I_B	Base current		0.5	A
P_{tot}	Total dissipation at $T_C = 25$ °C		160	W
T_{stg}	Storage temperature		-65 to 200	°C
T_J	Max. operating junction temperature		200	°C

For PNP type voltage and current values are negative

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction-case Max	1.09	°C/W

2 Electrical characteristics

($T_{\text{case}} = 25\text{ °C}$; unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CEV}	Collector cut-off current ($V_{\text{BE}} = -1.5\text{ V}$)	$V_{\text{CE}} = 100\text{ V}$ $V_{\text{CE}} = 100\text{ V}$ $T_{\text{c}} = 150\text{ °C}$			0.5 5	mA mA
I_{CEO}	Collector cut-off current ($I_{\text{B}} = 0$)	$V_{\text{CE}} = 50\text{ V}$			1	mA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = 5\text{ V}$			2	mA
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 100\text{ mA}$	100			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 10\text{ A}$ $I_{\text{B}} = 40\text{ mA}$ $I_{\text{C}} = 20\text{ A}$ $I_{\text{B}} = 200\text{ mA}$			2 3	V V
$V_{\text{BE(sat)}}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 20\text{ A}$ $I_{\text{B}} = 200\text{ mA}$			4	V
$V_{\text{BE}}^{(1)}$	Base-emitter voltage	$I_{\text{C}} = 10\text{ A}$ $V_{\text{CE}} = 3\text{ V}$			2.8	V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 10\text{ A}$ $V_{\text{CE}} = 3\text{ V}$ $I_{\text{C}} = 20\text{ A}$ $V_{\text{CE}} = 3\text{ V}$	750 100		18000	
h_{fe}	Small signal current gain	$I_{\text{C}} = 10\text{ A}$ $V_{\text{CE}} = 3\text{ V}$ $f = 1\text{ kHz}$	300			
C_{CBO}	Collector-base capacitance ($I_{\text{E}} = 0$)	$V_{\text{CB}} = 10\text{ V}$ $f = 100\text{ kHz}$ for 2N6284 for 2N6287			400 600	pF pF

1. Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

For PNP type voltage and current values are negative

2.1 Electrical characteristics (curves)

Figure 2. DC current gain (NPN type)

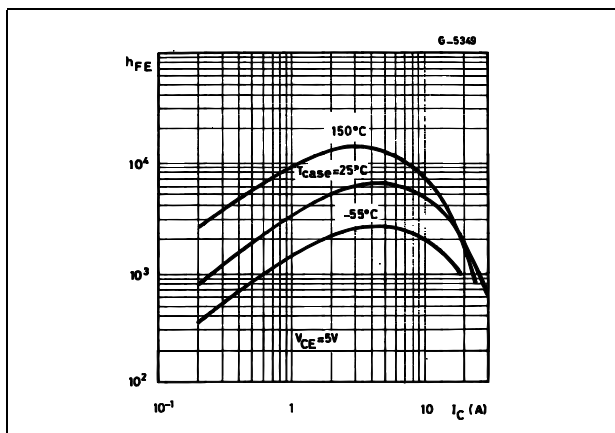


Figure 3. DC current gain (PNP type)

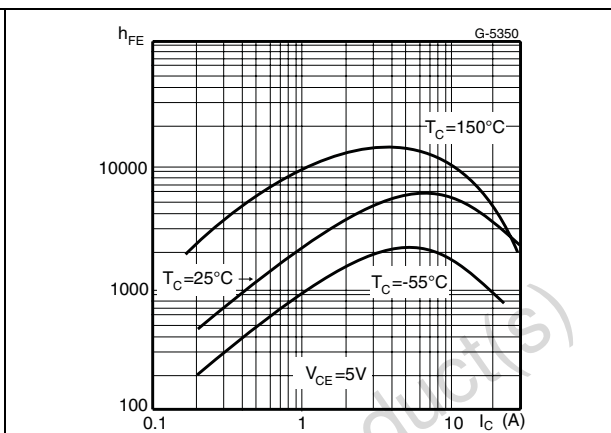


Figure 4. DC current gain (NPN type)

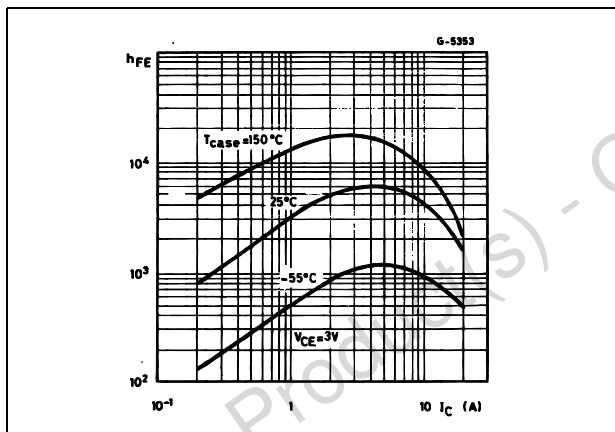


Figure 5. DC current gain (PNP type)

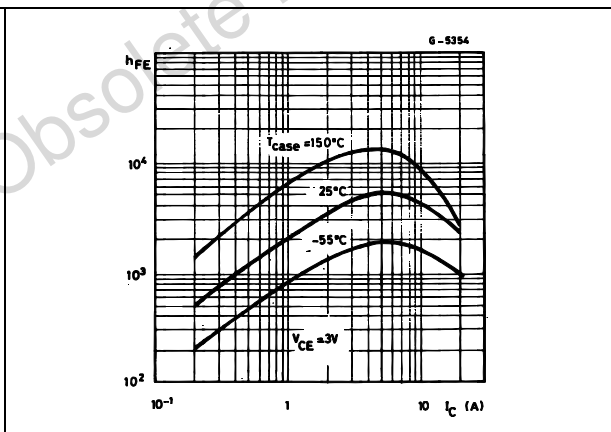


Figure 6. Collector-emitter saturation voltage (NPN type)

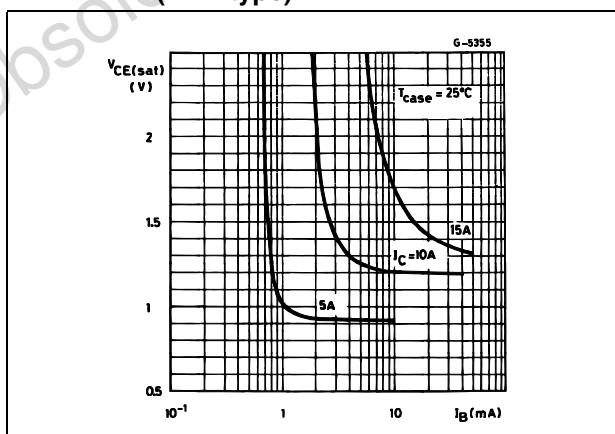
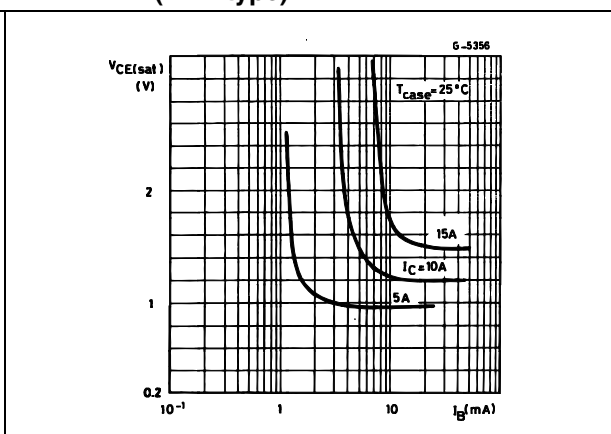


Figure 7. Collector-emitter saturation voltage (PNP type)



3 Package mechanical data

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Obsolete Product(s) - Obsolete Product(s)

4 Revision history

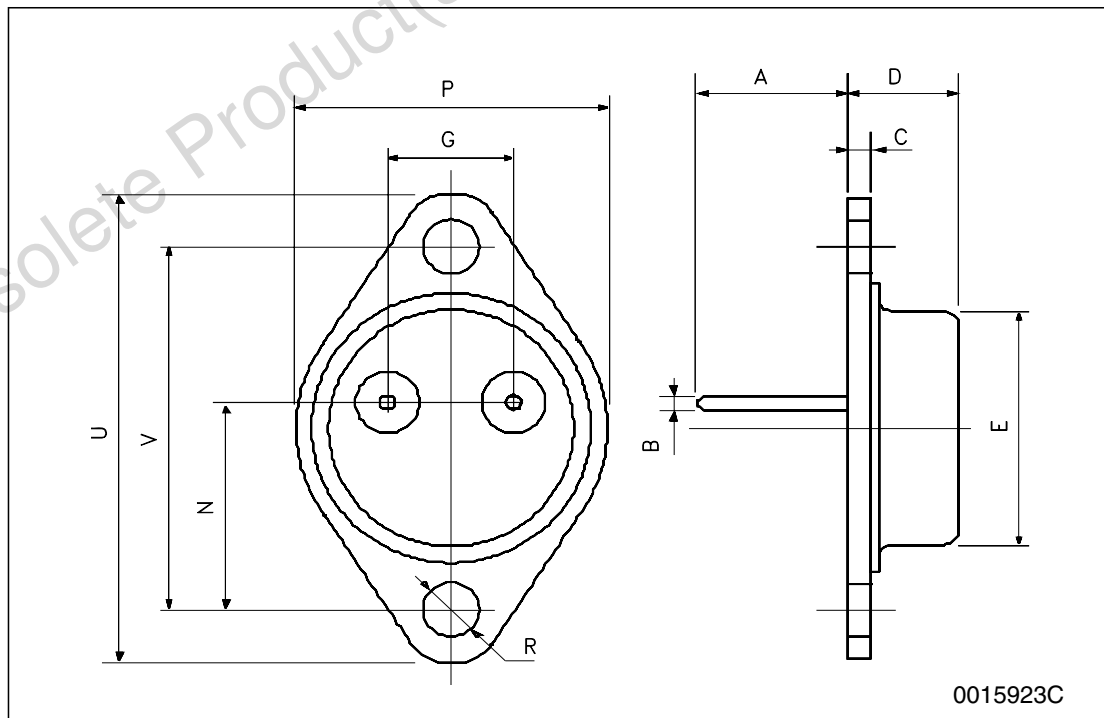
Table 5. Document revision history

Date	Revision	Changes
02-Mar-2000	2	
26-Jan-2009	3	Added paragraph 2.1

Obsolete Product(s) - Obsolete Product(s)

TO-3 mechanical data

DIM.	mm.		
	min.	typ	max.
A	11.00		13.10
B	0.97		1.15
C	1.50		1.65
D	8.32		8.92
E	19.00		20.00
G	10.70		11.10
N	16.50		17.20
P	25.00		26.00
R	4.00		4.09
U	38.50		39.30
V	30.00		30.30



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